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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/643,690	08/19/2003	Yoshiyuki Kurokawa	0553-0323.01	5081
7590 07/22/2005		EXAMINER WILSON, ALLAN R		
Edward D. Manzo Cook, Alex, McFarron, Manzo, Cummings & Mehler, Ltd. 200 West Adams St., Ste. 2850 Chicago, IL 60606				
			ART UNIT	PAPER NUMBER
			2815	-
			DATE MAILED: 07/22/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

H.D						
	Application No.	Applicant(s)				
	10/643,690	KUROKAWA ET AL.				
Office Action Summary	Examiner	Art Unit				
	Allan R. Wilson	2815				
The MAILING DATE of this communication Period for Reply	appears on the cover sheet w	ith the correspondence address				
A SHORTENED STATUTORY PERIOD FOR RE THE MAILING DATE OF THIS COMMUNICATIO - Extensions of time may be available under the provisions of 37 CFI after SIX (6) MONTHS from the mailing date of this communication - If the period for reply specified above is less than thirty (30) days, a - If NO period for reply is specified above, the maximum statutory pe - Failure to reply within the set or extended period for reply will, by st Any reply received by the Office later than three months after the m earned patent term adjustment. See 37 CFR 1.704(b).	NN. R 1.136(a). In no event, however, may a . I reply within the statutory minimum of thi riod will apply and will expire SIX (6) MOI atute, cause the application to become A	reply be timely filed rty (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 1	<u>6 May 2005</u> .					
2a)⊠ This action is FINAL . 2b)□ ⁻	☐ This action is FINAL. 2b)☐ This action is non-final.					
closed in accordance with the practice und	er <i>Ex par</i> te Quayle, 1935 C.I	D. 11, 453 O.G. 213.				
Disposition of Claims						
4) Claim(s) 1,4,6,7,10-13,16-19,21,24-27,43,44 and 46-50 is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.						
	i)⊠ Claim(s) <u>1,4,6,13,16-19,21,24-27,43,44 and 46-50</u> is/are allowed.					
<u> </u>	☐ Claim(s) 7 and 10-12 is/are rejected.					
8) Claim(s) are subject to restriction ar	id/or election requirement.	*				
Application Papers						
9) The specification is objected to by the Exam						
10) The drawing(s) filed on is/are: a)						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).						
11) The oath or declaration is objected to by the	· · · · · · · · · · · · · · · · · · ·					
	Examiner. Note the attache	d Office Action of form 1 10-132.				
Priority under 35 U.S.C. § 119						
 12) ☐ Acknowledgment is made of a claim for fore a) ☐ All b) ☐ Some * c) ☐ None of: 1.☐ Certified copies of the priority docum 		§ 119(a)-(d) or (f).				
2. Certified copies of the priority docum	ents have been received in A	Application No				
3. Copies of the certified copies of the p	priority documents have been	received in this National Stage				
application from the International Bu	, , , , , , , , , , , , , , , , , , , ,					
* See the attached detailed Office action for a	list of the certified copies not	received.				
Attachment(s)	· <u> </u>					
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) Paper No(s)/Mail Date						
 2) \(\sum \) Notice of Draftsperson's Patent Drawing Review (P10-948) 3) \(\sum \) Information Disclosure Statement(s) (PTO-1449 or PTO/SB 	nformal Patent Application (PTO-152)					
Paper No(s)/Mail Date 6) Other:						

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DETAILED ACTION

Claim Objections

Claim 43 is objected to because of the following informalities: Claim 43, line 13 should be amended to have --in-- inserted after "not". Appropriate correction is required.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 7 and 10-12 are rejected under 35 U.S.C. 102(b) as being anticipated by 5,215,934 to Tzeng. Tzeng teaches, with reference to figures 5 and 6, a memory transistor comprising:

an active layer 20, comprising a source 36, drain 37 and channel forming region (inherently formed between 36 and 37);

- a first insulating film 30/31 formed on the active layer;
- a floating gate 33 formed on the first insulating film;
- a second insulating film (not shown, col. 6, lines 23-28); and
- a control gate 35 formed on the second insulating film;
- a first region 25a and a second region 25b formed in the channel forming region;

wherein a concentration of impurity elements in the first region is larger than a concentration of impurity elements in the second region (see the limitations of Tzeng, claim 26, citing that the threshold voltages differ between channel portions, and see col. 7, lines 2-6 teaching that the threshold difference is achieved by ion implantation), and wherein the impurity elements are any one of P-type impurity elements and N-type impurity elements (see col. 6, lines 4-8).

Regarding claim 10, this claim cites functional limitations which may be achieved by the structure of Tzeng; as taught by applicant, the function of storing multi-value information is achieved by applying different programming voltages, not by a difference in structure over that taught by Tzeng. Regarding claim 11, Tzeng teaches that the substrate 20 is single crystal silicon (col. 5, lines 39-41). Regarding claim 12, this claim merely cites intended uses of the structure anticipated by Tzeng and does not distinguish over Tzeng.

Allowable Subject Matter

Claims 1, 4, 6, 13, 16-19, 21, 24-27, 43, 44, 46 and 47-50 are allowed.

Response to Arguments

Applicant's arguments filed 05/16/2005 have been fully considered but they are not persuasive.

The argument that Tzeng fails to disclose or suggest "the impurity elements are any one of P-type impurity elements and N-type impurity elements" is not persuasive. Tzeng discloses in col. 6, lines 4-8, "[o]ther species are also effective in enhancing the thermal oxidation rate.

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Antimony, argon, arsenic, and boron, or any one of the group III-IV dopants, have proven effective for enhancing oxidation rates in silicon." Therefore, Tzeng teaches impurity elements are one of P-type impurity elements or N-type impurity elements.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Note: The present case has been transferred to a different examiner.

Any inquiry concerning this communication or earlier communications from an examiner should be directed to Primary Examiner Allan Wilson whose telephone number is (571) 272-1738. Examiner Wilson can normally be reached 7:00-4:00 Monday-Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Allan R. Wilson Primary Examiner Page 5

20 July 2005